CMOS Digital Integrated Circuits Silicon Monolithic

# TC74VHC02FK

### 1. Functional Description

• Quad 2-Input NOR Gate

#### 2. General

The TC74VHC02FK is an advanced high speed CMOS 2-INPUT NOR GATE fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

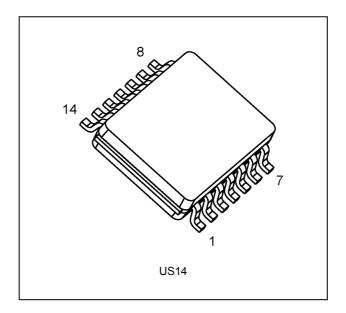
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

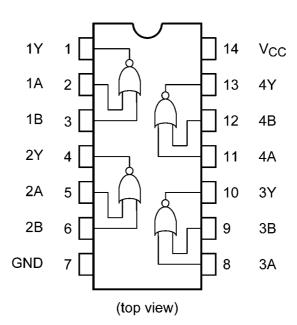
### 3. Features

- (1) High speed: Propagation delay time = 3.6 ns (typ.) at  $V_{CC}$  = 5.0 V
- (2) Low power dissipation:  $I_{CC} = 2.0 \ \mu A \ (max)$  at  $T_a = 25 \ ^{\circ}C$
- (3) High noise immunity:  $V_{\rm NIH} = V_{\rm NIL} = 28 \% V_{\rm CC}$  (min)
- (4) Power-down protection is provided on all inputs.
- (5) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (6) Wide operating voltage range:  $V_{CC(opr)} = 2.0$  to 5.5 V
- (7) Low noise:  $V_{OLP} = 0.8 V (max)$
- (8) Pin and function compatible with 74 series (74AC/VHC/HC/F/ALS/LS etc.) 02 type

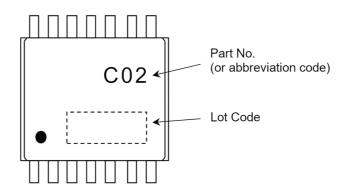
#### 4. Packaging



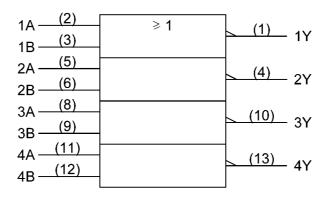
## 5. Pin Assignment



## 6. Marking



7. IEC Logic Symbol



### 8. Truth Table

| Input<br>A | Input<br>B | Output<br>Y |
|------------|------------|-------------|
| L          | L          | Н           |
| L          | Н          | L           |
| Н          | L          | L           |
| Н          | Н          | L           |

## 9. Absolute Maximum Ratings (Note)

| Characteristics                 | Symbol           | Rating                        | Unit |
|---------------------------------|------------------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  | -0.5 to 7.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  | -0.5 to 7.0                   | V    |
| Output voltage                  | V <sub>OUT</sub> | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current             | I <sub>IK</sub>  | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  | ±20                           | mA   |
| Output current                  | I <sub>OUT</sub> | ±25                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  | ±50                           | mA   |
| Power dissipation               | PD               | 180                           | mW   |
| Storage temperature             | T <sub>stg</sub> | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## 10. Operating Ranges (Note)

| Characteristics           | Symbol           | Test Condition             | Rating               | Unit |
|---------------------------|------------------|----------------------------|----------------------|------|
| Supply voltage            | V <sub>CC</sub>  | —                          | 2.0 to 5.5           | V    |
| Input voltage             | V <sub>IN</sub>  | —                          | 0 to 5.5             | V    |
| Output voltage            | V <sub>OUT</sub> |                            | 0 to V <sub>CC</sub> | V    |
| Operating temperature     | T <sub>opr</sub> | —                          | -40 to 85            | °C   |
| Input rise and fall times | dt/dv            | $V_{CC}$ = 3.3 ± 0.3 V     | 0 to 100             | ns/V |
|                           |                  | $V_{CC}$ = 5.0 $\pm$ 0.5 V | 0 to 20              |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

## **11. Electrical Characteristics**

## 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics           | Symbol          | Test Condition                       |                          | V <sub>CC</sub> (V) | Min                 | Тур. | Max                 | Unit |
|---------------------------|-----------------|--------------------------------------|--------------------------|---------------------|---------------------|------|---------------------|------|
| High-level input voltage  | V <sub>IH</sub> | —                                    |                          | 2.0                 | 1.50                | _    | —                   | V    |
|                           |                 |                                      |                          | 3.0 to 5.5          | $V_{CC} \times 0.7$ | _    | —                   |      |
| Low-level input voltage   | V <sub>IL</sub> | —                                    |                          | 2.0                 | —                   | _    | 0.50                | V    |
|                           |                 |                                      |                          | 3.0 to 5.5          | —                   |      | $V_{CC} \times 0.3$ |      |
| High-level output voltage | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IL</sub>    | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                 | 2.0  | —                   | V    |
|                           |                 |                                      |                          | 3.0                 | 2.9                 | 3.0  | —                   |      |
|                           |                 |                                      |                          | 4.5                 | 4.4                 | 4.5  | —                   |      |
|                           |                 |                                      | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.58                |      | —                   |      |
|                           |                 |                                      | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.94                |      | —                   |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OL</sub> = 50 μA  | 2.0                 | —                   | 0.0  | 0.1                 | V    |
|                           |                 |                                      |                          | 3.0                 | —                   | 0.0  | 0.1                 |      |
|                           |                 |                                      |                          | 4.5                 | —                   | 0.0  | 0.1                 |      |
|                           |                 |                                      | I <sub>OL</sub> = 4 mA   | 3.0                 | —                   | _    | 0.36                |      |
|                           |                 |                                      | I <sub>OL</sub> = 8 mA   | 4.5                 | _                   | _    | 0.36                |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND       |                          | 0 to 5.5            | —                   |      | ±0.1                | μA   |
| Quiescent supply current  | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND             |                          | 5.5                 | _                   |      | 2.0                 | μA   |

## 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics           | Symbol          | Test Condition                       |                          | V <sub>CC</sub> (V) | Min                | Max                 | Unit |
|---------------------------|-----------------|--------------------------------------|--------------------------|---------------------|--------------------|---------------------|------|
| High-level input voltage  | V <sub>IH</sub> | —                                    |                          | 2.0                 | 1.50               | —                   | V    |
|                           |                 |                                      |                          | 3.0 to 5.5          | $V_{CC} 	imes 0.7$ | _                   |      |
| Low-level input voltage   | VIL             | —                                    |                          | 2.0                 | _                  | 0.50                | V    |
|                           |                 |                                      |                          | 3.0 to 5.5          |                    | $V_{CC} \times 0.3$ |      |
| High-level output voltage | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IL</sub>    | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                | —                   | V    |
|                           |                 |                                      |                          | 3.0                 | 2.9                | —                   |      |
|                           |                 |                                      |                          | 4.5                 | 4.4                | —                   |      |
|                           |                 |                                      | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.48               | —                   |      |
|                           |                 |                                      | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.80               | —                   |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OL</sub> = 50 μA  | 2.0                 |                    | 0.1                 | V    |
|                           |                 |                                      |                          | 3.0                 |                    | 0.1                 |      |
|                           |                 |                                      |                          | 4.5                 |                    | 0.1                 |      |
|                           |                 |                                      | I <sub>OL</sub> = 4 mA   | 3.0                 | _                  | 0.44                |      |
|                           |                 |                                      | I <sub>OL</sub> = 8 mA   | 4.5                 |                    | 0.44                |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND       |                          | 0 to 5.5            |                    | ±1.0                | μA   |
| Quiescent supply current  | I <sub>CC</sub> | $V_{IN} = V_{CC}$ or GND             |                          | 5.5                 | _                  | 20.0                | μA   |

### 11.3. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol                             | Note     | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|-------------------------------|------------------------------------|----------|-------------------------------|---------------------|-----|------|------|------|
| Propagation delay time        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  |     | 5.6  | 7.9  | ns   |
|                               |                                    |          |                               | 50                  | _   | 8.1  | 11.4 |      |
|                               |                                    |          | $5.0\pm0.5$                   | 15                  | _   | 3.6  | 5.5  |      |
|                               |                                    |          |                               | 50                  | _   | 5.1  | 7.5  |      |
| Input capacitance             | C <sub>IN</sub>                    |          | —                             |                     | _   | 4    | 10   | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                    | (Note 1) | _                             |                     | _   | 15   | _    | pF   |

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per gate)

## 11.4. AC Characteristics

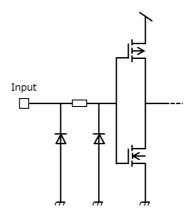
## (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | V <sub>CC</sub> (V)           | $C_L (pF)$ | Min | Max  | Unit |
|------------------------|------------------------------------|-------------------------------|------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $\textbf{3.3}\pm\textbf{0.3}$ | 15         | 1.0 | 9.5  | ns   |
|                        |                                    |                               | 50         | 1.0 | 13.0 |      |
|                        |                                    | $5.0\pm0.5$                   | 15         | 1.0 | 6.5  |      |
|                        |                                    |                               | 50         | 1.0 | 8.5  |      |
| Input capacitance      | C <sub>IN</sub>                    | —                             |            |     | 10   | pF   |

#### 11.5. Noise Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Characteristics                          | Symbol           | Test Condition         | V <sub>CC</sub> (V) | Тур. | Limit | Unit |
|------------------------------------------|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic $V_{OL}$    | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.3  | 0.8   | V    |
| Quiet output minimum dynamic $V_{OL}$    | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.3 | -0.8  | V    |
| Minimum high-level dynamic input voltage | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 3.5   | V    |
| Maximum low-level dynamic input voltage  | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 1.5   | V    |

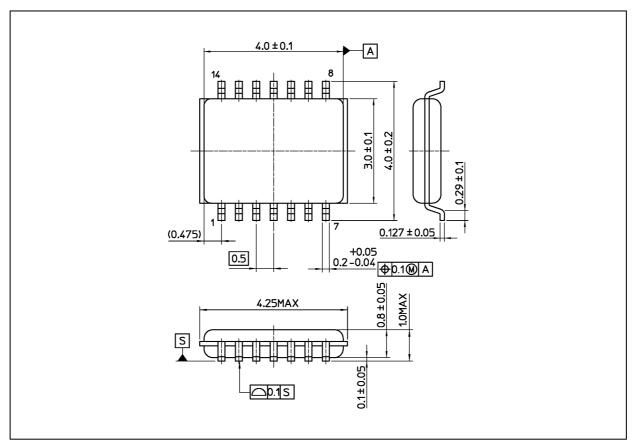
#### 11.6. Input Equivalent Circuit



## TC74VHC02FK

## Package Dimensions

Unit: mm



#### Weight: 0.02 g (typ.)

|                | Package Name(s) |
|----------------|-----------------|
| Nickname: US14 |                 |

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